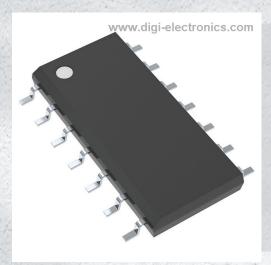


## MC3303DR2 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number MC3303DR2-DG

Manufacturer onsemi

Manufacturer Product Number MC3303DR2

Description IC OPAMP QUAD DIFF INPUT 14SOIC

Detailed Description General Purpose Amplifier 4 Circuit 14-SOIC



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
MC3303DR2	onsemi
Series:	Product Status:
	Obsolete
Amplifier Type:	Number of Circuits:
General Purpose	4
Output Type:	Slew Rate:
	0.6V/µs
Gain Bandwidth Product:	Current - Input Bias:
1 MHz	200 nA
Voltage - Input Offset:	Current - Supply:
2 mV	2.8mA (x4 Channels)
Current - Output / Channel:	Voltage - Supply Span (Min):
30 mA	3 V
Voltage - Supply Span (Max):	Operating Temperature:
36 V	-40°C ~ 85°C
Mounting Type:	Package / Case:
Surface Mount	14-SOIC (0.154", 3.90mm Width)
Supplier Device Package:	Base Product Number:
14-SOIC	MC3303

## **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
RoHS non-compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

8542.33.0001

## Onsemi

www.onsemi.com

## **Single Supply Quad Operational Amplifiers**

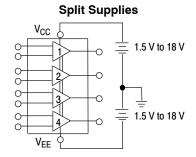
### MC3403, MC3303

The MC3403 is a low cost, quad operational amplifier with true differential inputs. The device has electrical characteristics similar to the popular MC1741C. However, the MC3403 has several distinct advantages over standard operational amplifier types in single supply applications. The quad amplifier can operate at supply voltages as low as 3.0 V or as high as 36 V with quiescent currents about one third of those associated with the MC1741C (on a per amplifier basis). The common mode input range includes the negative supply, thereby eliminating the necessity for external biasing components in many applications. The output voltage range also includes the negative power supply voltage.

#### **Features**

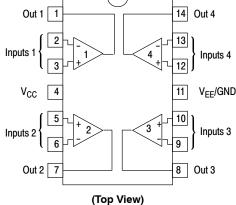
- Short Circuit Protected Outputs
- Class AB Output Stage for Minimal Crossover Distortion
- True Differential Input Stage
- Single Supply Operation: 3.0 V to 36 V • Split Supply Operation: ±1.5 V to ±18 V • Low Input Bias Currents: 500 nA Max
- Four Amplifiers Per Package
- Internally Compensated
- Similar Performance to Popular MC1741C
- Industry Standard Pin-outs
- ESD Diodes Added for Increased Ruggedness
- Pb-Free Packages are Available

# Single Supply 3.0 V to 36 V VEE, GND

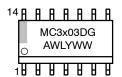




# PIN CONNECTIONS



#### **MARKING DIAGRAM**



= 3 or 4

= Assembly Location

= Wafer Lot = Year WW = Work Week

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 8.

#### **MAXIMUM RATINGS**

Symbol	Rating	Value	Unit
V <sub>CC</sub> V <sub>CC</sub> , V <sub>EE</sub>	Power Supply Voltages Single Supply Split Supplies	36 ±18	Vdc
V <sub>IDR</sub>	Input Differential Voltage Range (Note 1)	±36	Vdc
V <sub>ICR</sub>	Input Common Mode Voltage Range (Notes 1 and 2)	±18	Vdc
T <sub>stg</sub>	Storage Temperature Range	-55 to +125	°C
T <sub>A</sub>	Operating Ambient Temperature Range MC3303 MC3403	-40 to +85 0 to +70	°C
TJ	Junction Temperature	150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Split power supplies.
 For supply voltages less than ±18 V, the absolute maximum input voltage is equal to the supply voltage.

#### **ELECTRICAL CHARACTERISTICS**

 $(V_{CC} = +15 \text{ V}, V_{EE} = -15 \text{ V} \text{ for MC3403}; V_{CC} = +14 \text{ V}, V_{EE} = GND \text{ for MC3303 } T_A = 25^{\circ}C, \text{ unless otherwise noted.})$ 

			MC3403			MC3303		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Unit
V <sub>IO</sub>	Input Offset Voltage $T_A = T_{high}$ to $T_{low}$ (Note 3)	_ _	2.0 -	10 12	- -	2.0 -	8.0 10	mV
I <sub>IO</sub>	Input Offset Current $T_A = T_{high}$ to $T_{low}$	_ _	30 -	50 200	- -	30 -	75 250	nA
A <sub>VOL</sub>	Large Signal Open Loop Voltage Gain $V_O = \pm 10$ V, $R_L = 2.0$ k $\Omega$ $T_A = T_{high}$ to $T_{low}$	20 15	200 -	- -	20 15	200 -	<u>-</u>	V/mV
I <sub>IB</sub>	Input Bias Current $T_A = T_{high}$ to $T_{low}$	- -	-200 -	-500 -800	- -	-200 -	-500 -1000	nA
Z <sub>O</sub>	Output Impedance f = 20 Hz	-	75	_	_	75	-	Ω
z <sub>i</sub>	Input Impedance f = 20 Hz	0.3	1.0	_	0.3	1.0	-	МΩ
V <sub>O</sub>	Output Voltage Range $\begin{array}{c} R_L = 10 \text{ k}\Omega \\ R_L = 2.0 \text{ k}\Omega \\ R_L = 2.0 \text{ k}\Omega, T_A = T_{high} \text{ to } T_{low} \end{array}$	±12 ±10 ±10	±13.5 ±13 -	- - -	12 10 10	12.5 12 -	- - -	V
V <sub>ICR</sub>	Input Common Mode Voltage Range	+13 V -V <sub>EE</sub>	+13 V -V <sub>EE</sub>	-	+12 V -V <sub>EE</sub>	+12.5 V -V <sub>EE</sub>	-	٧
CMR	Common Mode Rejection $R_S \le 10 \text{ k}\Omega$	70	90	-	70	90	-	dB
I <sub>CC</sub> , I <sub>EE</sub>	Power Supply Current ( $V_0 = 0$ ) $R_L = \infty$	-	2.8	7.0	-	2.8	7.0	mA
I <sub>SC</sub>	Individual Output Short-Circuit Current (Note 4)	±10	±20	±45	±10	±30	±45	mA
PSRR+	Positive Power Supply Rejection Ratio	-	30	150	-	30	150	μV/V
PSRR-	Negative Power Supply Rejection Ratio	-	30	150	-	30	150	μV/V
$\Delta I_{IO}/\Delta T$	Average Temperature Coefficient of Input Offset Current T <sub>A</sub> = T <sub>high</sub> to T <sub>low</sub>	-	50	-	-	50	-	pA/°C
$\Delta V_{IO}/\Delta T$	Average Temperature Coefficient of Input Offset Voltage T <sub>A</sub> = T <sub>high</sub> to T <sub>low</sub>	-	10	-	-	10	-	μV/°C
BWp	Power Bandwidth $A_{V}=1,\ R_{L}=10\ k\Omega,\ V_{O}=20\ V(p-p),\ THD$ = 5%	-	9.0	-	-	9.0	-	kHz
BW	Small–Signal Bandwidth $A_V = 1, \ R_L = 10 \ k\Omega, \ V_O = 50 \ mV$	-	1.0	-	-	1.0	-	MHz
SR	Slew Rate $A_V = 1$ , $V_i = -10 \text{ V}$ to $+10 \text{ V}$	-	0.6	_	_	0.6	-	V/μs
t <sub>TLH</sub>	Rise Time $A_V$ = 1, $R_L$ = 10 k $\Omega$ , $V_O$ = 50 mV	-	0.35	-	-	0.35	-	μs
t <sub>TLH</sub>	Fall Time $A_V = 1$ , $R_L = 10 \text{ k}\Omega$ , $V_O = 50 \text{ mV}$	-	0.35	_	_	0.35	-	μs
os	Overshoot A <sub>V</sub> = 1, R <sub>L</sub> = 10 k $\Omega$ , V <sub>O</sub> = 50 mV	-	20	-	-	20	-	%
φm	Phase Margin $A_V = 1$ , $R_L = 2.0 \text{ k}\Omega$ , $V_O = 200 \text{ pF}$	-	60	-	-	60	-	٥
-	Crossover Distortion $(V_{in} = 30 \text{ mVpp}, V_{out} = 2.0 \text{ Vpp}, f = 10 \text{ kHz})$	_	1.0	_	_	1.0	-	%

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. MC3303: T<sub>low</sub> = -40°C, T<sub>high</sub> = +85°C, MC3403: T<sub>low</sub> = 0°C, T<sub>high</sub> = +70°C

4. Not to exceed maximum package power dissipation.

#### **ELECTRICAL CHARACTERISTICS** ( $V_{CC}$ = 5.0 V, $V_{EE}$ = GND, $T_A$ = 25°C, unless otherwise noted.)

		MC3403		MC3303				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Unit
V <sub>IO</sub>	Input Offset Voltage	-	2.0	10	-	-	10	mV
I <sub>IO</sub>	Input Offset Current	-	30	50	-	-	75	nA
I <sub>IB</sub>	Input Bias Current	-	-200	-500	-	-	-500	nA
A <sub>VOL</sub>	Large Signal Open Loop Voltage Gain $R_L = 2.0 \ k\Omega$	10	200	-	10	200	-	V/mV
PSRR	Power Supply Rejection Ratio	-	-	150	-	-	150	μV/V
V <sub>OR</sub>	Output Voltage Range (Note 5) $R_L$ = 10 k $\Omega$ , $V_{CC}$ = 5.0 V $R_L$ = 10 k $\Omega$ , 5.0 ≤ $V_{CC}$ ≤ 30 V	3.3 V <sub>CC</sub> -2.0	3.5 V <sub>CC</sub> -1.7	- -	3.3 V <sub>CC</sub> -2.0	3.5 V <sub>CC</sub> -1.7	- -	V <sub>pp</sub>
I <sub>CC</sub>	Power Supply Current	-	2.5	7.0	_	2.5	7.0	mA
CS	Channel Separation f = 1.0 kHz to 20 kHz (Input Referenced)	_	-120	-	_	-120	-	dB

<sup>5.</sup> Output will swing to ground with a 10  $k\Omega$  pull down resistor.

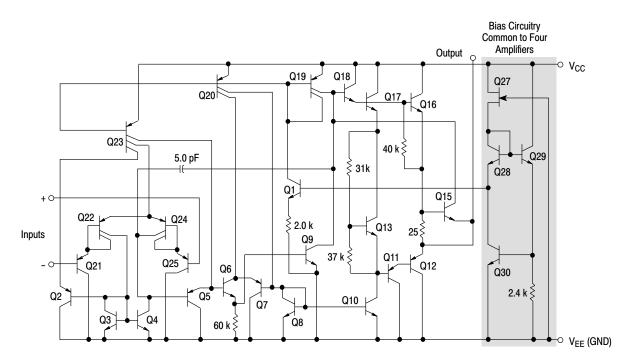


Figure 1. Representative Schematic Diagram (1/4 of Circuit Shown)

#### **CIRCUIT DESCRIPTION**

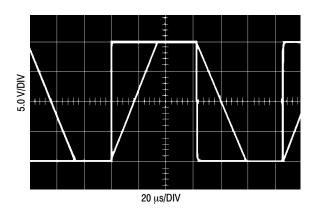


Figure 2. Inverter Pulse Response

The MC3403/3303 is made using four internally compensated, two-stage operational amplifiers. The first stage of each consists of differential input device Q24 and Q22 with input buffer transistors Q25 and Q21 and the differential to single ended converter Q3 and Q4. The first

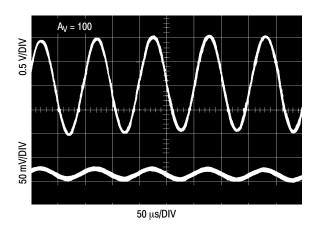


Figure 3. Sine Wave Response

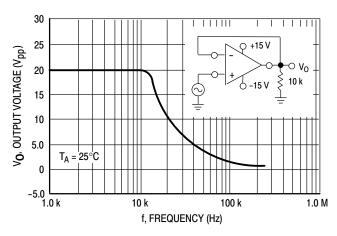


Figure 5. Power Bandwidth

stage performs not only the first stage gain function but also performs the level shifting and Transconductance reduction functions. By reducing the Transconductance, a smaller compensation capacitor (only 5.0 pF) can be employed, thus saving chip area. The Transconductance reduction is accomplished by splitting the collectors of Q24 and Q22. Another feature of this input stage is that the input common mode range can include the negative supply or ground, in single supply operation, without saturating either the input devices or the differential to single–ended converter. The second stage consists of a standard current source load amplifier stage.

The output stage is unique because it allows the output to swing to ground in single supply operation and yet does not exhibit any crossover distortion in split supply operation. This is possible because Class AB operation is utilized.

Each amplifier is biased from an internal voltage regulator which has a low temperature coefficient, thus giving each amplifier good temperature characteristics as well as excellent power supply rejection.

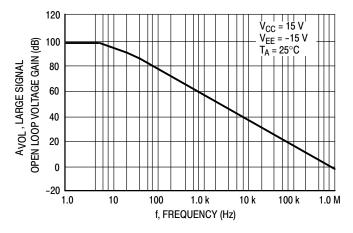


Figure 4. Open Loop Frequency Response

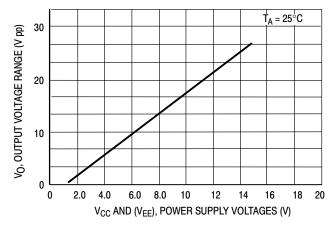


Figure 6. Output Swing versus Supply Voltage

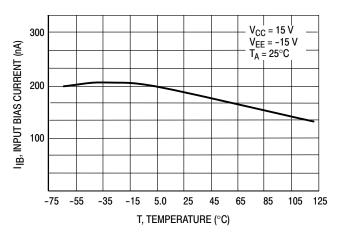


Figure 7. Input Bias Current versus Temperature

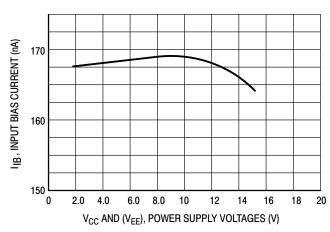


Figure 8. Input Bias Current versus Supply Voltage

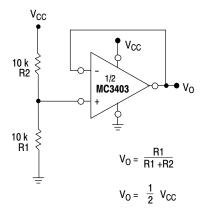


Figure 9. Voltage Reference

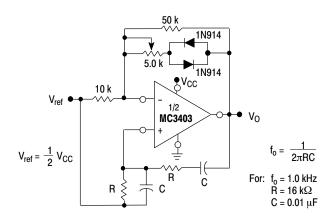


Figure 10. Wien Bridge Oscillator

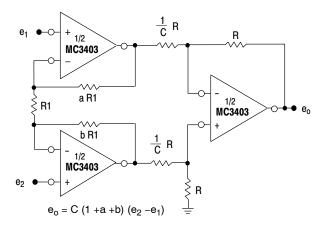


Figure 11. High Impedance Differential Amplifier

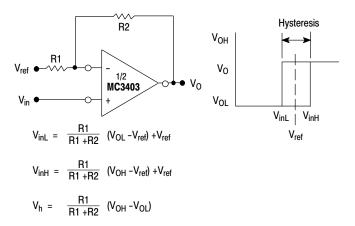


Figure 12. Comparator with Hysteresis

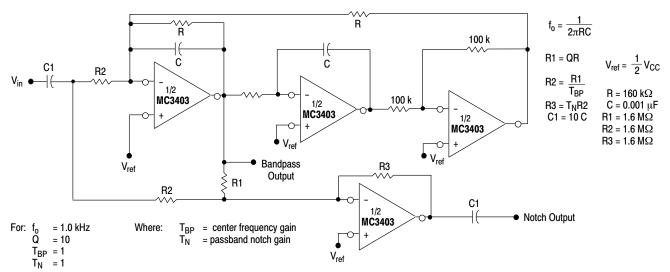


Figure 13. Bi-Quad Filter

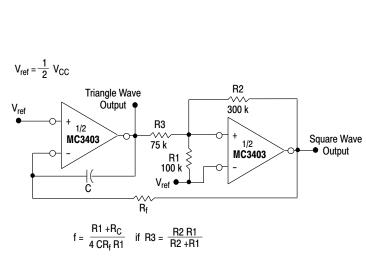
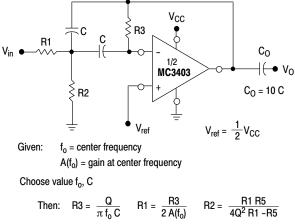


Figure 14. Function Generator



For less than 10% error from operational amplifier  $\frac{O_0 f_0}{BW} < 0.1$  where  $f_0$  and BW are expressed in Hz.

If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

Figure 15. Multiple Feedback Bandpass Filter

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MC3303DR2G	SOIC-14 (Pb-Free)	2,500 Tape & Reel
MC3403DR2G	SOIC-14 (Pb-Free)	2,500 Tape & Reel

#### **DISCONTINUED** (Note 6)

MC3303D	SOIC-14	
MC3303DG	SOIC-14 (Pb-Free)	55 Units / Rail
MC3303DR2	SOIC-14	2,500 Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging

Specifications Brochure, <u>BRD8011/D</u>.

6. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.



## **MECHANICAL CASE OUTLINE**

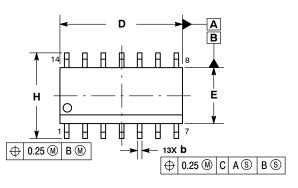
PACKAGE DIMENSIONS

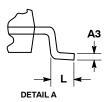


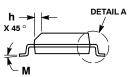
△ 0.10

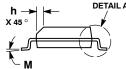
SOIC-14 NB CASE 751A-03 ISSUE L

**DATE 03 FEB 2016** 





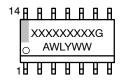




- NOTES:
  1. DIMENSIONING AND TOLERANCING PER
  - ASME Y14.5M, 1994.
    CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT
- MAXIMUM MATERIAL CONDITION.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
- 5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
АЗ	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
Е	3.80	4.00	0.150	0.157
œ	1.27	1.27 BSC		BSC
Н	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
М	0 °	7°	0 °	7 °

#### **GENERIC MARKING DIAGRAM\***



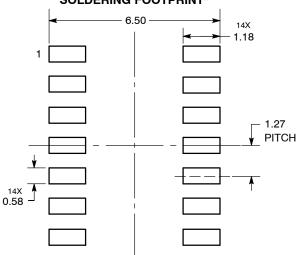
XXXXX = Specific Device Code Α = Assembly Location

WL = Wafer Lot Υ = Year WW = Work Week = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

#### **SOLDERING FOOTPRINT\***

C SEATING PLANE



DIMENSIONS: MILLIMETERS \*For additional information on our Pb-Free strategy and soldering

details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **STYLES ON PAGE 2**

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#### SOIC-14 CASE 751A-03 ISSUE L

#### DATE 03 FEB 2016

STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

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